NSN 5961-01-241-6591

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Inclosure Material:

Plastic

Overall Length:

0.360 inches

Terminal Length:

0.510 inches

Overall Height:

0.105 inches

Overall Width:

0.410 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-202

Internal Junction Configuration:

Npn

Mounting Method:

Terminal and unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, collector-to-base, emitter open and 300.0 breakdown voltage, collector-to-emitter, base open and 8.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

500.00 milliamperes source cutoff current and 250.00 milliamperes source cutoff current

Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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